

PMF63UNE 20 V, N-channel Trench MOSFET 20 April 2016

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- LED driver
- Power management
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	2.2	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 2 A; T _j = 25 °C		-	57	65	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	souce		
3	D	drain	1 2 SC-70 (SOT323)	G S 017aaa255

6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
PMF63UNE	SC-70	plastic surface-mounted package; 3 leads	SOT323		

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMF63UNE	Z%V

[1] % = placeholder for manufacturing site code

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8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	2.2	А
		V_{GS} = 4.5 V; T_{amb} = 25 °C	[1]	-	2	А
		V_{GS} = 4.5 V; T_{amb} = 100 °C	[1]	-	1.3	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	8	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	300	mW
			[1]	-	395	mW
		T _{sp} = 25 °C		-	1.8	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
I _S	source current	T _{amb} = 25 °C	[1]	-	0.37	Α

Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².
 Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

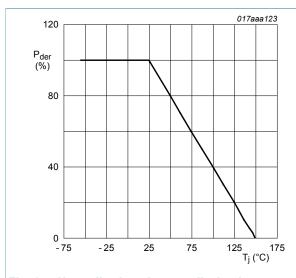
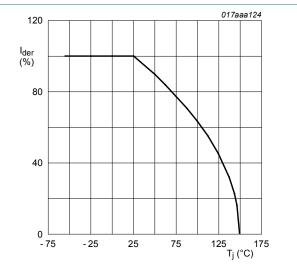


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

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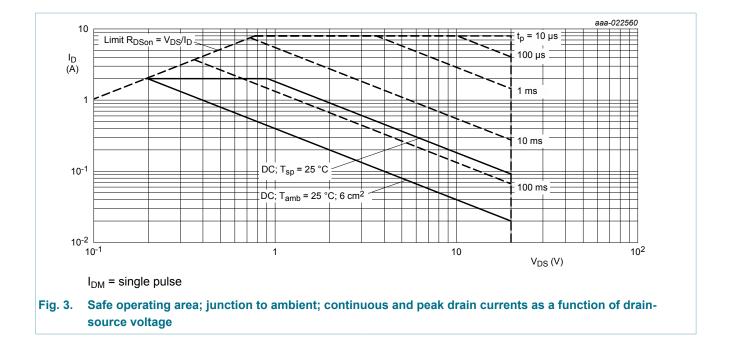


$$I_{der} = \frac{I_D}{I_D(25^{\circ}C)} \times 100 \%$$

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9. Thermal characteristics

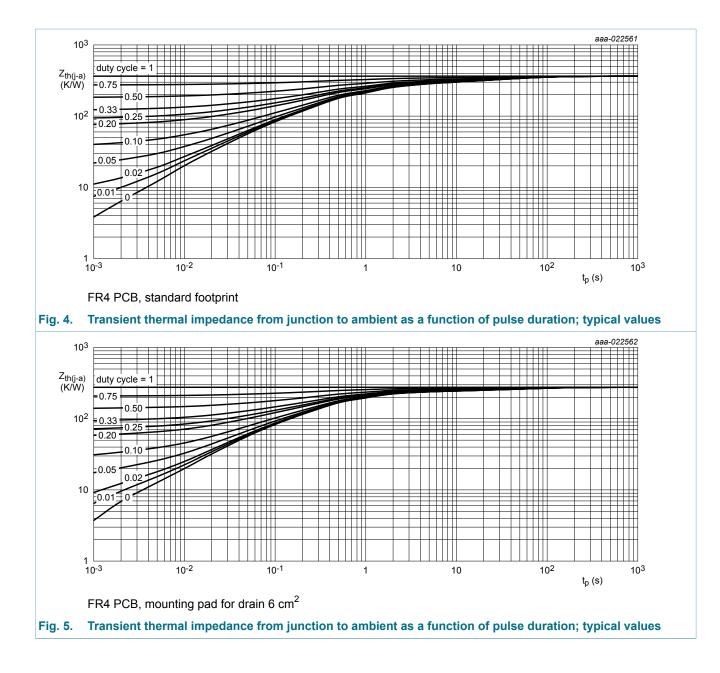
Table 6. T	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistance	in free air	[1]	-	363	418	K/W
	from junction to		[2]	-	276	317	K/W
	ampient	in free air; t ≤ 5 s	[2]	-	238	273	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	60	69	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



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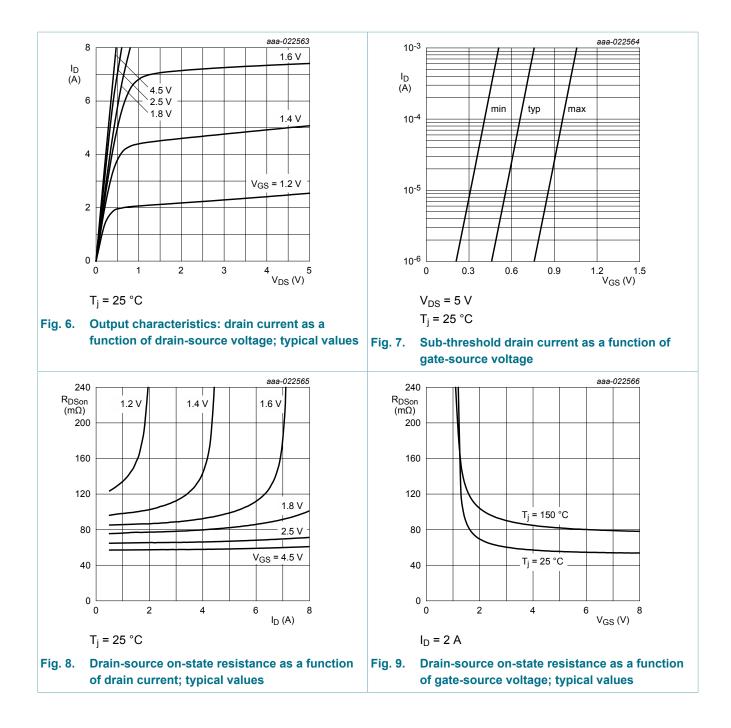
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	0.45	0.7	1	V
I _{DSS}	drain leakage current	V_{DS} = 20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; T _j = 25 °C	-	-	10	μA
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	5	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-5	μA
R _{DSon}	drain-source on-state	V _{GS} = 4.5 V; I _D = 2 A; T _j = 25 °C	-	57	65	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 2 A; T _j = 150 °C	-	84	96	mΩ
		V _{GS} = 2.5 V; I _D = 1.8 A; T _j = 25 °C	-	64	74	mΩ
		V _{GS} = 1.8 V; I _D = 0.8 A; T _j = 25 °C	-	78	88	mΩ
9 _{fs}	forward transconductance	V _{DS} = 5 V; I _D = 2 A; T _j = 25 °C	-	9	-	S
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	-	1.8	-	Ω
Dynamic ch	aracteristics					
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 2 A; V _{GS} = 4.5 V;	-	3.9	5.85	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.3	-	nC
Q _{GD}	gate-drain charge		-	0.9	-	nC
C _{iss}	input capacitance	V _{DS} = 10 V; f = 1 MHz; V _{GS} = 0 V;	-	289	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	51	-	pF
C _{rss}	reverse transfer capacitance	-	-	42	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; I _D = 2 A; V _{GS} = 4.5 V;	-	8	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	27	-	ns
t _{d(off)}	turn-off delay time		-	35	-	ns
t _f	fall time		-	19	-	ns
Source-drai	n diode					
V _{SD}	source-drain voltage	I _S = 0.37 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

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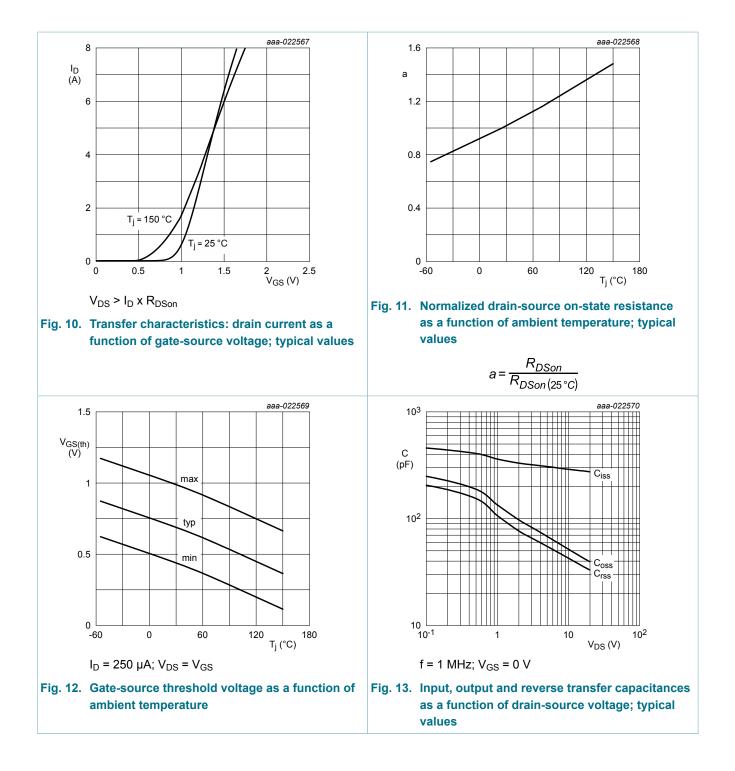
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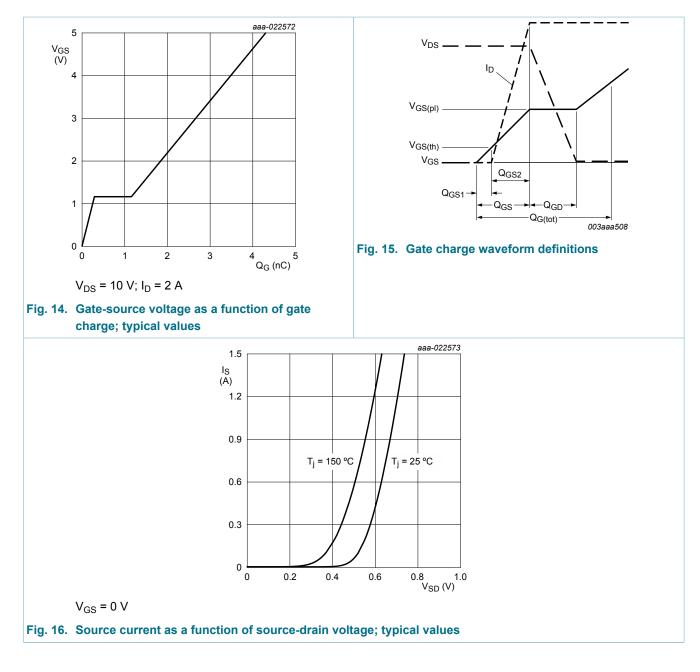
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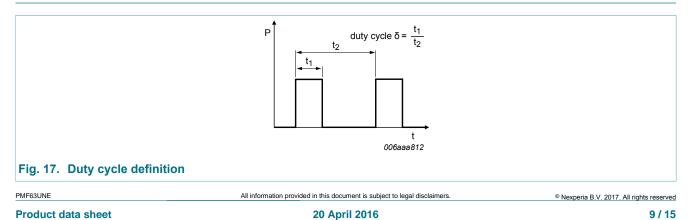
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11. Test information



12. Package outline

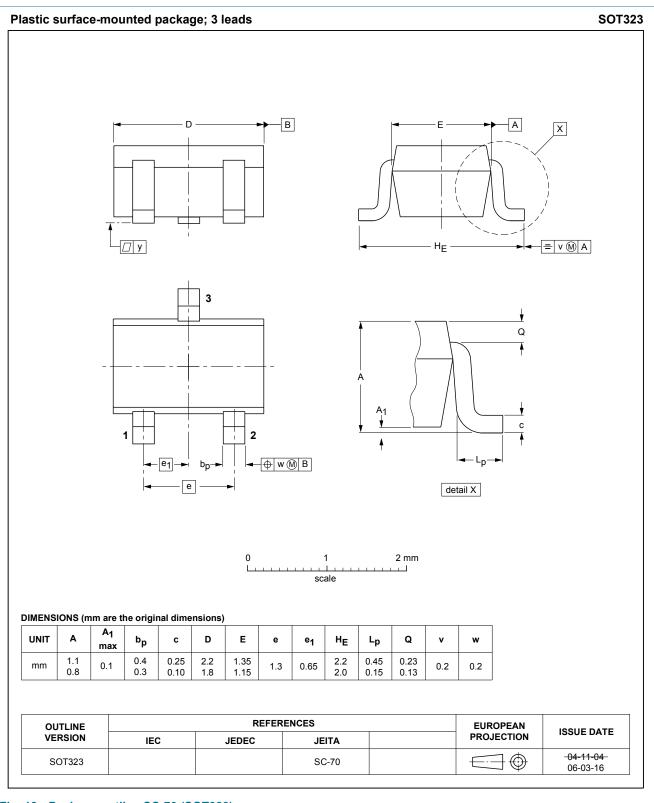
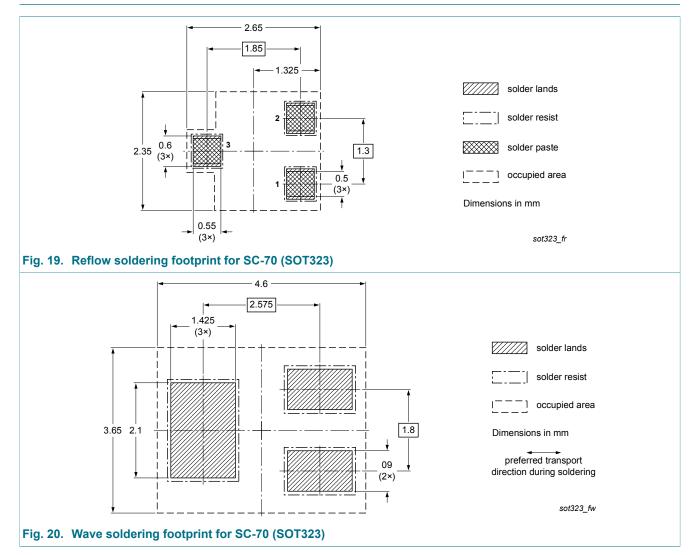


Fig. 18. Package outline SC-70 (SOT323) PMF63UNE All ir

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13. Soldering



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14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMF63UNE v.1	20160420	Product data sheet	-	-

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15. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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